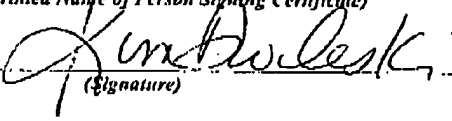


DEC 27 2004

CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)			Docket No.
Applicant(s): Farquhar et al.			EN9-98-122US3
Application No. 09/781,730	Filing Date 2/12/2001	Examiner Goff II, John L.	Group Art Unit 1733
Invention: SEMICONDUCTOR DEVICE HAVING A THERMOSET-CONTAINING DIELECTRIC MATERIAL AND METHODS FOR FABRICATING THE SAME			
I hereby certify that this <u>Response to Interview Summary (1 page)</u> (Identify type of correspondence)			
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Examiner: Goff II, John L.

Serial No.: 09/781,730

Art Unit: 1733

Filed: 2/12/01

**For: SEMICONDUCTOR DEVICE HAVING A THERMOSET-CONTAINING
DIELECTRIC MATERIAL AND METHODS FOR FABRICATING THE SAME**

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Response to Interview Summary

Sir:

Applicant's Representative acknowledges that the Interview Summary mailed December 22, 2004 relating to the Interview on December 16, 2004 between the Examiner and Applicant's Representative is accurate.

Date: 12/27/2004

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09/781,730